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Molybdenum Ditelluride (MoTe₂) is a semimetallic transition-metal dichalcogenide (TMD) that can be found in two different structural phases, differing in the layer stacking angle: the monoclinic β -MoTe₂ and the orthorhombic γ -MoTe₂. A phase change from γ to β is expected in bulk MoTe₂ at a temperature of around 240 K [1]. To probe if this structural phase-change also happens in few-layer crystals and to understand its impact on the band structure of this material, we perform temperature-dependent magnetoresistance measurements on mechanically exfoliated few-layer γ -MoTe₂. We verify that the amplitude of the second-harmonic resistance signal scales with the strength of the magnetic field. This is consistent with the bilinear magnetoelectric resistance (BMR) effect, as reported before for WTe₂[2] and Bi₂Se₃[3]. The BMR effect is an important tool to explore the spin-dependent band structure of a material. Our results show a sinusoidal behaviour of the second-harmonic resistance signal as a function of the magnetic field angle, indicating an in-plane spin component consistent with a Rashba-like system (Fig 1). Moreover, we observe a sign change between 150 and 300 K, indicating a possible effect from a structural phase transition.

References

- [1] HP Hughes and RH Friend, J. Phys. C: Solid State Phys., 11 (1978) L103
- [2] P He, CH Hsu, S Shi et al, Nat. Comm., 10 (2019) 1290
- [3] P He, SS-L Zhang, D Zhu et al, Nat. Phys., 14 (2018) 495

Figures

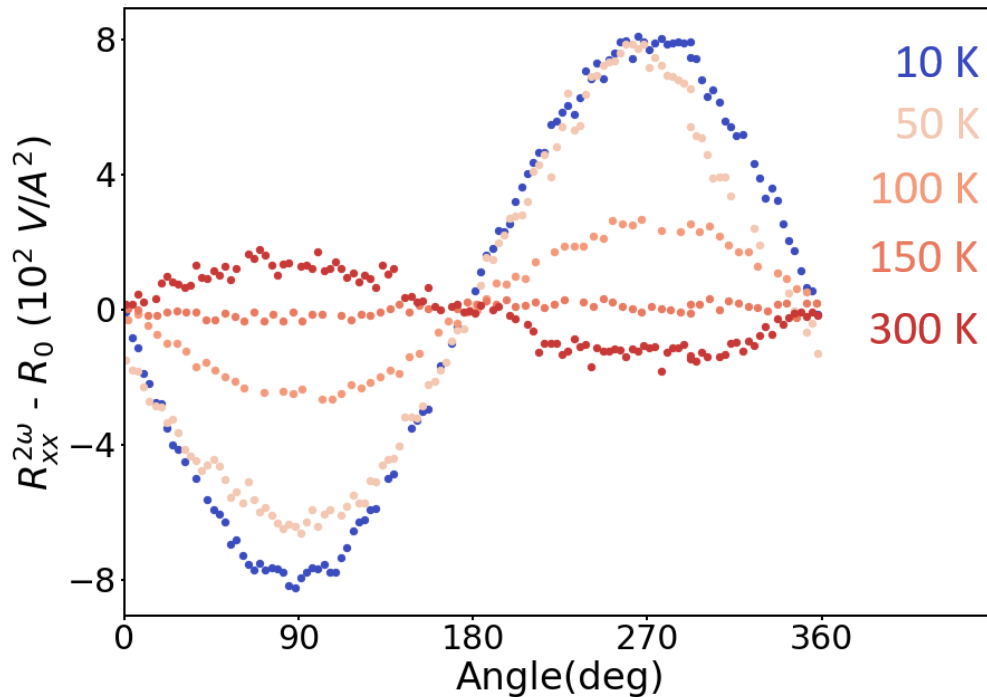


Figure 1: Second harmonic resistance measurement as a function of temperature in few-layer MoTe₂.